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BLF7G22L-130; Power LDMOS transistor Rev. 5 — 1 September 2015

AMPLEON

Product data sheet

Product profile

1.1 General description

130 W LDMOS power transistor for base station applications at frequencies from 2000 MHz to 2200 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

| Mode of operation | f | I _{Dq} | V _{DS} | $P_{L(AV)}$ | Gp | η_{D} | ACPR |
|-------------------|--------------|-----------------|-----------------|-------------|------|------------|----------------------|
| | (MHz) | (mA) | (V) | (W) | (dB) | (%) | (dBc) |
| 2-carrier W-CDMA | 2110 to 2170 | 950 | 28 | 30 | 18.5 | 32 | -32 ^[1] |
| 1-carrier W-CDMA | 2110 to 2170 | 950 | 28 | 33 | 18.5 | 33 | -39 <mark>[2]</mark> |

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (2000 MHz to 2200 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for W-CDMA base stations and multi carrier applications in the 2000 MHz to 2200 MHz frequency range

^[2] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.

2. Pinning information

Table 2. Pinning

| Table 2. | | | | |
|----------|------------------|------------|--------------------|--|
| Pin | Description | | Simplified outline | Graphic symbol |
| BLF7G22I | L-130 (SOT502A) | | | |
| 1 | drain | | | , |
| 2 | gate | | | , <u>, </u> |
| 3 | source | <u>[1]</u> | | 2 - |
| | | | | 3 sym112 |
| D | 0.400.400.700.70 | | | Sym112 |
| BLF/G22I | LS-130 (SOT502B) | | | |
| 1 | drain | | | _ |
| 2 | gate | | 3 | , <u>, </u> |
| 3 | source | <u>[1]</u> | | 2 |
| | | | | 3 |
| | | | | sym112 |

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | | | |
|---------------|---------|---|---------|--|--|--|--|--|
| | Name | Description | Version | | | | | |
| BLF7G22L-130 | - | flanged LDMOST ceramic package; 2 mounting holes; 2 leads | SOT502A | | | | | |
| BLF7G22LS-130 | - | earless flanged LDMOST ceramic package; 2 leads | SOT502B | | | | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|------|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| V_{GS} | gate-source voltage | | -0.5 | +13 | V |
| I_{D} | drain current | | - | 28 | Α |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 225 | °C |

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|--|----------------------------------|------|------|
| $R_{\text{th(j-c)}}$ | thermal resistance from junction to case | T_{case} = 80 °C; P_L = 30 W | 0.35 | K/W |

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|----------------------------------|--|-----|------|------|------|
| V _{(BR)DSS} | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 1.5 \text{ mA}$ | 65 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | V_{DS} = 10 V; I_{D} = 150 mA | 1.3 | 1.8 | 2.3 | V |
| I _{DSS} | drain leakage current | $V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$ | - | - | 5 | μА |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$ | 25 | 29.5 | - | Α |
| I _{GSS} | gate leakage current | V_{GS} = 11 V; V_{DS} = 0 V | - | - | 450 | nA |
| 9 _{fs} | forward transconductance | V_{DS} = 10 V; I_{D} = 7.5 A | - | 10 | 11 | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 5.25 A$ | - | 0.1 | 0.16 | Ω |

7. Test information

Table 7. Functional test information

Mode of operation: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH; f_1 = 2112.5 MHz; f_2 = 2117.5 MHz; f_3 = 2162.5 MHz; f_4 = 2167.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 950 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-------------|------------------------------|---------------------------|-----|------|-----|------|
| $P_{L(AV)}$ | average output power | | - | 30 | - | W |
| Gp | power gain | P _{L(AV)} = 30 W | 17 | 18.5 | - | dB |
| RLin | input return loss | P _{L(AV)} = 30 W | - | -15 | -9 | dB |
| η_{D} | drain efficiency | P _{L(AV)} = 30 W | 29 | 32 | - | % |
| ACPR | adjacent channel power ratio | P _{L(AV)} = 30 W | - | -31 | -28 | dBc |

7.1 Ruggedness in class-AB operation

The BLF7G22L-130 and BLF7G22LS-130 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 950 \text{ mA}$; $P_L = 130 \text{ W}$ (CW); f = 2110 MHz.

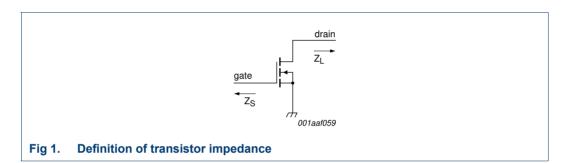
7.2 Impedance information

Table 8. Typical impedance information

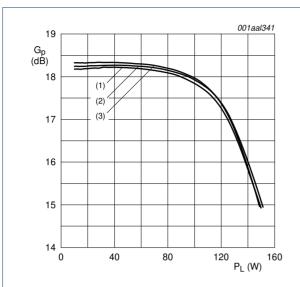
 $I_{Dq} = 950 \text{ mA}$; main transistor $V_{DS} = 28 \text{ V}$.

 Z_S and Z_L defined in Figure 1.

| f (MHz) | Z _S (Ω) | Z _L (Ω) |
|------------|--------------------|-----------------------|
| 2050 | 1.3 – j3.6 | 2.2 – j2.6 |
| 2140 | 1.9 – j4.2 | 2.0 – j2.6 |
| 2230 | 3.1 – j4.7 | 1.9 – j2.8 |



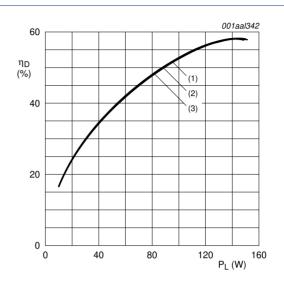
7.3 1 Tone CW



 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

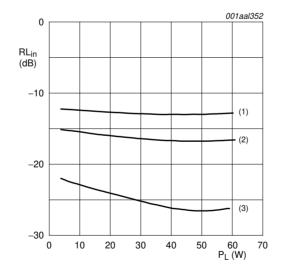
Fig 2. Power gain as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 3. Drain efficiency as a function of load power; typical values



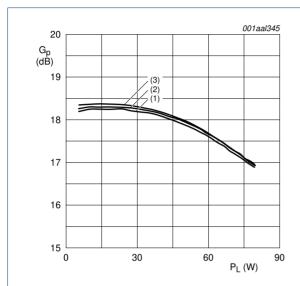
 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 4. Input return loss as a function of load power; typical values

7.4 1-carrier W-CDMA

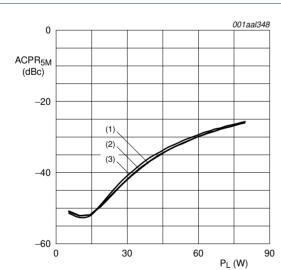
Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.



 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

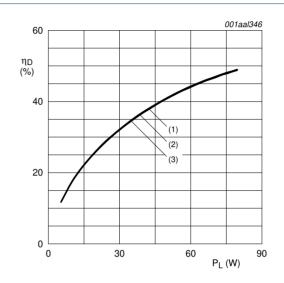
Fig 5. Power gain as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

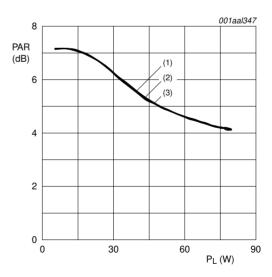
Fig 7. Adjacent channel power ratio (5MHz) as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 6. Drain efficiency as a function of load power; typical values



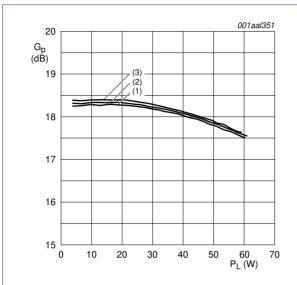
 $V_{DS} = 28 \text{ V}; I_{Dq} = 950 \text{ mA}.$

- (1) f = 2112.5 MHz
- (2) f = 2140 MHz
- (3) f = 2167.5 MHz

Fig 8. Peak-to-average power ratio as a function of load power; typical values

7.5 2-carrier W-CDMA (5 MHz carrier spacing)

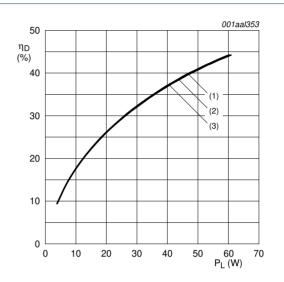
Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF.



V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 5 MHz.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

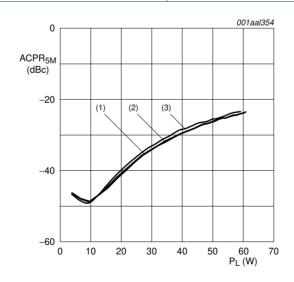
Power gain as a function of load power; Fig 9. typical values



V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 5 MHz.

- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 10. drain efficiency as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 5 MHz.

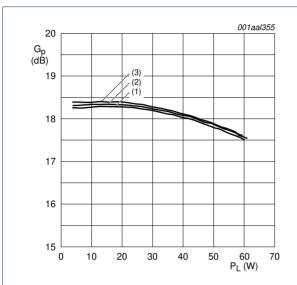
- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 11. Adjacent channel power ratio (5 MHz) as a function of load power; typical values

7 of 15

7.6 2-carrier W-CDMA (10 MHz carrier spacing)

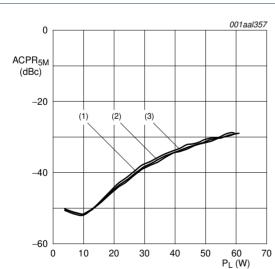
Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF.



 V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 10 MHz.

- (1) f = 2117.5 MHz
- (2) f = 2140 MHz
- (3) f = 2162.5 MHz

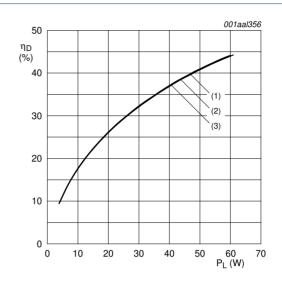
Fig 12. Power gain as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 10 MHz.

- (1) f = 2117.5 MHz
- (2) f = 2140 MHz
- (3) f = 2162.5 MHz

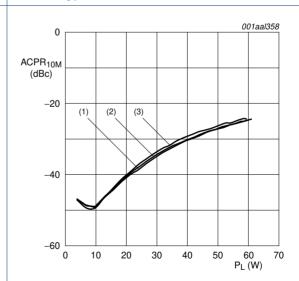
Fig 14. Adjacent channel power ratio (5 MHz) as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 10 MHz.

- (1) f = 2117.5 MHz
- (2) f = 2140 MHz
- (3) f = 2162.5 MHz

Fig 13. Drain efficiency as a function of load power; typical values

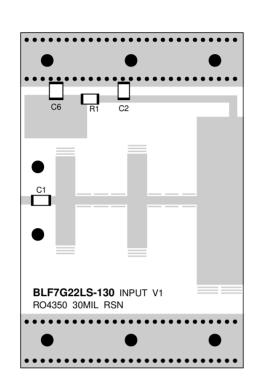


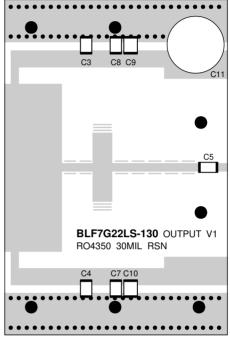
 V_{DS} = 28 V; I_{Dq} = 950 mA; carrier spacing 10 MHz.

- (1) f = 2117.5 MHz
- (2) f = 2140 MHz
- (3) f = 2162.5 MHz

Fig 15. Adjacent channel power ratio (10 MHz) as a function of load power; typical values

7.7 Test circuit





001aal359

See Table 9 for list of components. The drawing is not to scale.

Fig 16. Component layout

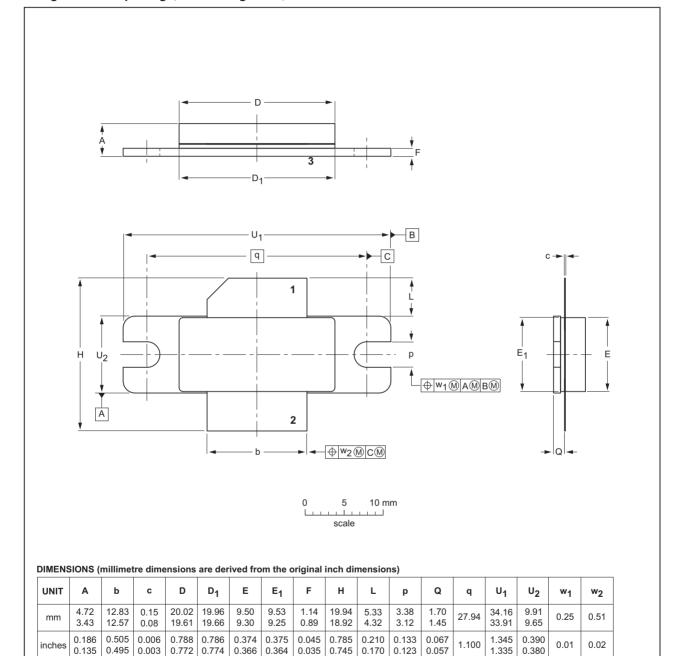
Table 9. List of components
See Figure 16 for component layout.

| Component | Description | Value | Remarks |
|--------------------|-----------------------------------|--------------|--------------|
| C1, C2, C3, C4, C5 | multilayer ceramic chip capacitor | 9.1 pF | ATC100B |
| C6, C7 | multilayer ceramic chip capacitor | 220 nF | AVX1206 |
| C8, C9, C10 | multilayer ceramic chip capacitor | 4.7 μF; 50 V | Kemet |
| C11 | electrolytic capacitor | 220 μF; 63 V | ВС |
| R1 | SMD resistor | 6.2 Ω | Philips 1206 |

8. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

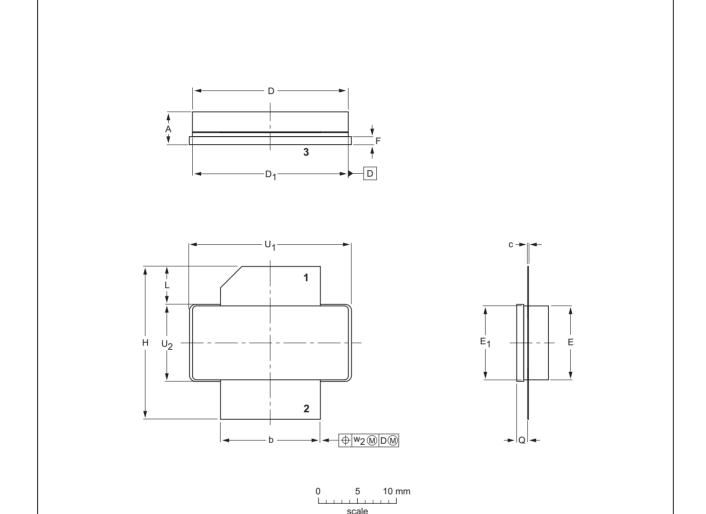


| OUTLINE | | REFERENCES EUROPEAN | | | | ISSUE DATE |
|---------|-----|---------------------|-------|--|------------|------------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT502A | | | | | | -03-01-10 - 12-05-02 |

Fig 17. Package outline SOT502A

Earless flanged ceramic package; 2 leads

SOT502B



DIMENSIONS (millimetre dimensions are derived from the original inch dimensions)

| UNIT | Α | b | С | D | D ₁ | E | E ₁ | F | н | L | Q | U ₁ | U ₂ | w ₂ |
|--------|--------------|----------------|--------------|----------------|----------------|--------------|----------------|--------------|----------------|--------------|--------------|----------------|----------------|----------------|
| mm | 4.72 3.43 | 12.83 12.57 | 0.15 0.08 | 20.02 19.61 | 19.96 19.66 | 9.50 9.30 | 9.53 9.25 | 1.14 0.89 | 19.94 18.92 | 5.33 4.32 | 1.70 1.45 | 20.70 20.45 | 9.91 9.65 | 0.25 |
| inches | | | | | | | | | 0.785 0.745 | | | | 0.390 0.380 | 0.010 |

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-------|-------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | 1330E DATE |
| SOT502B | | | | | 07-05-09 12-05-02 |

Fig 18. Package outline SOT502B

9. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| 3GPP | Third Generation Partnership Project |
| CCDF | Complementary Cumulative Distribution Function |
| CW | Continuous Wave |
| DPCH | Dedicated Physical CHannel |
| ESD | ElectroStatic Discharge |
| LDMOS | Laterally Diffused Metal Oxide Semiconductor |
| LDMOST | Laterally Diffused Metal Oxide Semiconductor Transistor |
| PAR | Peak-to-Average power Ratio |
| RF | Radio Frequency |
| SMD | Surface Mounted Device |
| VSWR | Voltage Standing Wave Ratio |
| W-CDMA | Wideband Code Division Multiple Access |

10. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|-----------------------------|--|--------------------|---------------|---------------------------------|--|
| BLF7G22L-130_7G22LS-130#5 | 20150901 | Product data sheet | - | BLF7G22L-130_7G22 LS-130 v.4 | |
| Modifications: | The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | |
| BLF7G22L-130_7G22LS-130 v.4 | 20110120 | Product data sheet | - | BLF7G22LS-130 v.3 | |
| BLF7G22L-130_7G22LS-130 v.3 | 20101118 | Product data sheet | - | BLF7G22LS-130 v.2 | |
| BLF7G22L-130_7G22LS-130 v.2 | 20101004 | Product data sheet | - | BLF7G22LS-130 v.1 | |
| BLF7G22LS-130 v.1 | 20100202 | Product data sheet | - | - | |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLF7G22L-130 7G22LS-130#5

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BLF7G22L-130; BLF7G22LS-130

Power LDMOS transistor

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For sales office addresses, please visit: http://www.ampleon.com/sales

BLF7G22L-130; BLF7G22LS-130

AMPLEON

Power LDMOS transistor

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